

To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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BIPOLAR ANALOG INTEGRATED CIRCUIT
PC29xx Series

THREE TERMINAL LOW DROPOUT VOLTAGE REGULATOR

The PC29xx series of low dropout voltage three terminal positive regulators is constructed with PNP output transistor. The PC29xx series feature the ability to source 1 A of output current with a low dropout voltage of typically 0.7 V.

The power dissipation of the PC29xx series can be drastically reduced compared with the conventional three terminal positive voltage regulators that is constructed with NPN output transistor. Also, this series corresponds to the low voltage output (3.0 V, 3.3 V) which is not in the conventional low dropout regulators (PC24xxA series).

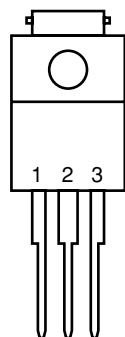
FEATURES

- Output current in excess of 1.0 A
- Low dropout voltage
 $V_{DIF} = 0.7 \text{ V TYP. (I}_o = 1 \text{ A)}$
- On-chip over-current and thermal protection circuit
- On-chip output transistor safe operating area protection circuit

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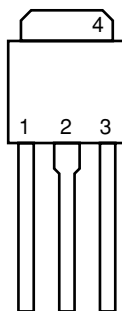
PIN CONFIGURATIONS (Marking Side)

PC29xxHF Series: Isolated TO-220 (MP-45G)



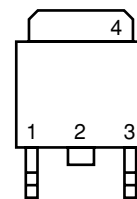
1: INPUT
 2: GND
 3: OUTPUT

PC29xxHB Series: SC-64 (MP-3)



1: INPUT
 2: GND^{Note1}
 3: OUTPUT
 4: GND (Fin)

PC29xxT Series: SC-63 (MP-3Z)

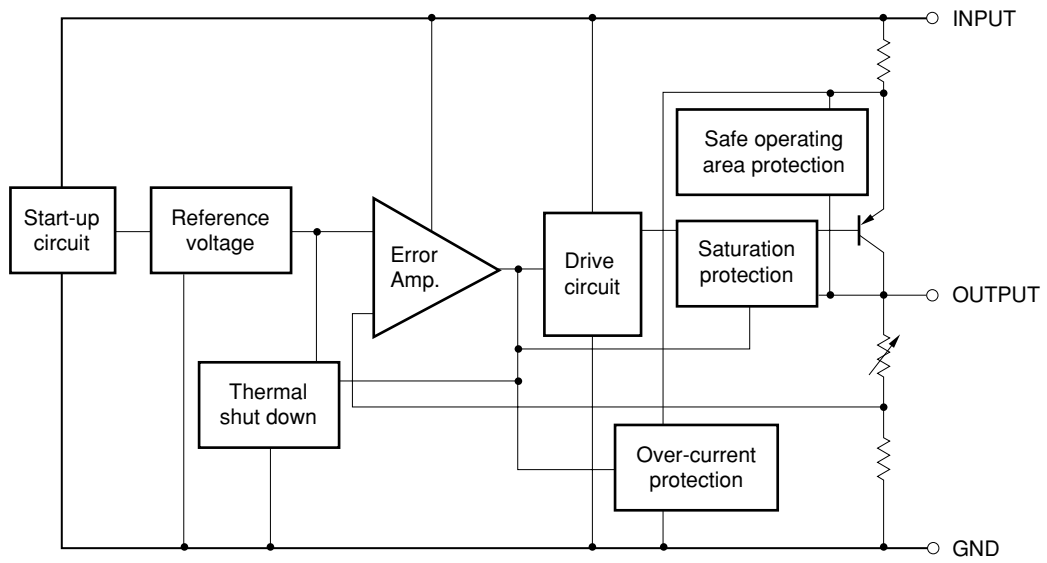


1: INPUT
 2: GND^{Note2}
 3: OUTPUT
 4: GND (Fin)

- Notes**
1. No.2 pin and No.4 fin are common GND.
 2. No.2 pin is cut. No.2 pin and No.4 fin are common GND.

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BLOCK DIAGRAM



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ORDERING INFORMATION

Part Number	Package	Output Voltage	Marking
μ PC2903HF	Isolated TO-220 (MP-45G)	3.0 V	2903
μ PC2903HB	SC-64 (MP-3)	3.0 V	2903
μ PC2903T	SC-63 (MP-3Z)	3.0 V	2903
μ PC2933HF	Isolated TO-220 (MP-45G)	3.3 V	2933
μ PC2933HB	SC-64 (MP-3)	3.3 V	2933
μ PC2933T	SC-63 (MP-3Z)	3.3 V	2933
μ PC2905HF	Isolated TO-220 (MP-45G)	5.0 V	2905
μ PC2905HB	SC-64 (MP-3)	5.0 V	2905
μ PC2905T	SC-63 (MP-3Z)	5.0 V	2905
μ PC2906HF	Isolated TO-220 (MP-45G)	6.0 V	2906
μ PC2906HB	SC-64 (MP-3)	6.0 V	2906
μ PC2906T	SC-63 (MP-3Z)	6.0 V	2906
μ PC2907HF	Isolated TO-220 (MP-45G)	7.0 V	2907
μ PC2907HB	SC-64 (MP-3)	7.0 V	2907
μ PC2907T	SC-63 (MP-3Z)	7.0 V	2907
μ PC2908HF	Isolated TO-220 (MP-45G)	8.0 V	2908
μ PC2908HB	SC-64 (MP-3)	8.0 V	2908
μ PC2908T	SC-63 (MP-3Z)	8.0 V	2908
μ PC2909HF	Isolated TO-220 (MP-45G)	9.0 V	2909
μ PC2909HB	SC-64 (MP-3)	9.0 V	2909
μ PC2909T	SC-63 (MP-3Z)	9.0 V	2909
μ PC2910HF	Isolated TO-220 (MP-45G)	10.0 V	2910
μ PC2910HB	SC-64 (MP-3)	10.0 V	2910
μ PC2910T	SC-63 (MP-3Z)	10.0 V	2910
μ PC2912HF	Isolated TO-220 (MP-45G)	12.0 V	2912
μ PC2912HB	SC-64 (MP-3)	12.0 V	2912
μ PC2912T	SC-63 (MP-3Z)	12.0 V	2912

Remark Tape-packaged products have the symbol -E1, or -E2 suffixed to the part number. Pb-free products have the symbol -AZ, or -AY suffixed to the part number. Refer to the following table for details.

Part Number ^{Note1}	Package	Package Type
μPC29xxHF	Isolated TO-220 (MP-45G)	• Packed in envelop
μPC29xxHF-AZ ^{Note2}	Isolated TO-220 (MP-45G)	• Packed in envelop
μPC29xxHB	SC-64 (MP-3)	• Packed in envelop
μPC29xxHB-AZ ^{Note2}	SC-64 (MP-3)	• Packed in envelop
μPC29xxHB-AY ^{Note3}	SC-64 (MP-3)	• Packed in envelop
μPC29xxT-E1	SC-63 (MP-3Z)	• 16 mm wide embossed taping • Pin 1 on draw-out side • 2000 pcs/reel
μPC29xxT-E1-AZ ^{Note2}	SC-63 (MP-3Z)	• 16 mm wide embossed taping • Pin 1 on draw-out side • 2000 pcs/reel
μPC29xxT-E1-AY ^{Note3}	SC-63 (MP-3Z)	• 16 mm wide embossed taping • Pin 1 on draw-out side • 2000 pcs/reel
μPC29xxT-E2	SC-63 (MP-3Z)	• 16 mm wide embossed taping • Pin 1 at take-up side • 2000 pcs/reel
μPC29xxT-E2-AZ ^{Note2}	SC-63 (MP-3Z)	• 16 mm wide embossed taping • Pin 1 at take-up side • 2000 pcs/reel
μPC29xxT-E2-AY ^{Note3}	SC-63 (MP-3Z)	• 16 mm wide embossed taping • Pin 1 at take-up side • 2000 pcs/reel

Notes 1. xx stands for symbols that indicate the output voltage.

2. Pb-free (This product does not contain Pb in the external electrode.)

3. Pb-free (This product does not contain Pb in the external electrode, Sn100% plating.)

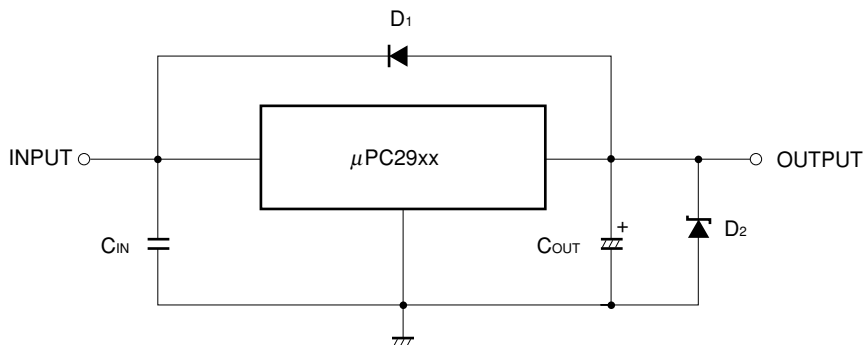
ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, Unless otherwise specified.)

Parameter	Symbol	Rating		Unit
		μPC29xxHF	μPC29xxHB, μPC29xxT	
Input Voltage	V _{IN}	20		V
Internal Power Dissipation (T _C = 25°C) Note	P _T	15	10	W
Operating Ambient Temperature	T _A	-30 to +85		°C
Operating Junction Temperature	T _J	-30 to +150		°C
Storage Temperature	T _{stg}	-55 to +150		°C
Thermal Resistance (Junction to Case)	R _{th (J-C)}	7	12.5	°C/W
Thermal Resistance (Junction to Ambient)	R _{th (J-A)}	65	125	°C/W

Note Internally limited. When the operating junction temperature rises above 150°C, the internal circuit shuts down the output voltage.

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

TYPICAL CONNECTION



- C_{IN} : 0.1 μF or higher. Be sure to connect C_{IN} to prevent parasitic oscillation. Set this value according to the length of the line between the regulator and the INPUT pin. Use of a film capacitor or other capacitor with first-rate voltage and temperature characteristics is recommended. If using a laminated ceramic capacitor, it is necessary to ensure that C_{IN} is 0.1 μF or higher for the voltage and temperature range to be used.
- C_{OUT} : 47 μF or higher. Be sure to connect C_{OUT} to prevent oscillation and improve excessive load regulation. Place C_{IN} and C_{OUT} as close as possible to the IC pins (within 1 to 2 cm). Also, use an electrolytic capacitor with low impedance characteristics if considering use at sub-zero temperatures.
- D₁ : If the OUTPUT pin has a higher voltage than the INPUT pin, connect a diode.
- D₂ : If the OUTPUT pin has a lower voltage than the GND pin, connect a Schottky barrier diode.

Caution Make sure that no voltage is applied to the OUTPUT pin from external.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Type Number	MIN.	TYP.	MAX.	Unit
Input Voltage	V _{IN}	μPC2903	4.0		16	V
		μPC2933	4.3		16	
		μPC2905	6		16	
		μPC2906	7		16	
		μPC2907	8		16	
		μPC2908	9		18	
		μPC2909	10		18	
		μPC2910	11		18	
		μPC2912	13		18	
Output Current	I _o	all	0		1.0	A
Operating Ambient Temperature	T _A	all	-30		+85	°C
Operating Junction Temperature	T _J	all	-30		+125	°C

ELECTRICAL CHARACTERISTICS

μPC2903 (T_J = 25°C, V_{IN} = 5 V, I_o = 500 mA, C_{IN} = 0.22 μF, C_{OUT} = 47 μF, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	V _O		2.88	3.0	3.12	V
		0°C ≤ T _J ≤ 125°C, 4.0 V ≤ V _{IN} ≤ 16 V, 0 A ≤ I _o ≤ 500 mA	2.85		3.15	
		0°C ≤ T _J ≤ 125°C, 0 A ≤ I _o ≤ 1 A				
Line Regulation	REG _{IN}	4.0 V ≤ V _{IN} ≤ 16 V		11	30	mV
Load Regulation	REG _L	0 A ≤ I _o ≤ 1 A		9	30	mV
Quiescent Current	I _{BIAS}	I _o = 0 A		1.9	4.0	mA
		I _o = 1 A		23	60	
Startup Quiescent Current	I _{BIAS (s)}	V _{IN} = 2.95 V, I _o = 0 A		12	30	mA
		V _{IN} = 2.95 V, I _o = 1 A			80	
Quiescent Current Change	ΔI _{BIAS}	0°C ≤ T _J ≤ 125°C, 4.0 V ≤ V _{IN} ≤ 16 V		3.2	20	mA
Output Noise Voltage	V _n	10 Hz ≤ f ≤ 100 kHz		52		μV _{r.m.s.}
Ripple Rejection	R·R	f = 120 Hz, 4.0 V ≤ V _{IN} ≤ 16 V	48	63		dB
Dropout Voltage	V _{DIF}	0°C ≤ T _J ≤ 125°C, I _o = 1 A		0.7	1.0	V
Short Circuit Current	I _{o short}	V _{IN} = 4.5 V	1.2	1.7	3.0	A
		V _{IN} = 16 V		1.2		
Peak Output Current	I _{o peak}	V _{IN} = 4.5 V	1.0	1.5	3.0	A
		V _{IN} = 16 V	1.3	1.7	2.8	
Temperature Coefficient of Output Voltage	ΔV _O /ΔT	0°C ≤ T _J ≤ 125°C, I _o = 5 mA		-0.5		mV/°C

μPC2933 ($T_J = 25^\circ\text{C}$, $V_{IN} = 5\text{ V}$, $I_O = 500\text{ mA}$, $C_{IN} = 0.22\ \mu\text{F}$, $C_{OUT} = 47\ \mu\text{F}$, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	V_O		3.17	3.3	3.43	V
		$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $4.3\text{ V} \leq V_{IN} \leq 16\text{ V}$, $0\text{ A} \leq I_O \leq 500\text{ mA}$	3.14		3.46	
		$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $0\text{ A} \leq I_O \leq 1\text{ A}$				
Line Regulation	REG_{IN}	$4.3\text{ V} \leq V_{IN} \leq 16\text{ V}$		12	33	mV
Load Regulation	REG_L	$0\text{ A} \leq I_O \leq 1\text{ A}$		23	33	mV
Quiescent Current	I_{BIAS}	$I_O = 0\text{ A}$		2.0	4.0	mA
		$I_O = 1\text{ A}$		30	60	
Startup Quiescent Current	$I_{BIAS(s)}$	$V_{IN} = 3.1\text{ V}$, $I_O = 0\text{ A}$		10	30	mA
		$V_{IN} = 3.1\text{ V}$, $I_O = 1\text{ A}$			80	
Quiescent Current Change	ΔI_{BIAS}	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $4.3\text{ V} \leq V_{IN} \leq 16\text{ V}$		3.0	20	mA
Output Noise Voltage	V_n	$10\text{ Hz} \leq f \leq 100\text{ kHz}$		55		$\mu\text{V}_{r.m.s.}$
Ripple Rejection	R·R	$f = 120\text{ Hz}$, $4.3\text{ V} \leq V_{IN} \leq 16\text{ V}$	48	64		dB
Dropout Voltage	V_{DIF}	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $I_O = 1\text{ A}$		0.7	1.0	V
Short Circuit Current	$I_{O\text{ short}}$	$V_{IN} = 4.5\text{ V}$	1.2	1.6	3.0	A
		$V_{IN} = 16\text{ V}$		1.2		
Peak Output Current	$I_{O\text{ peak}}$	$V_{IN} = 4.5\text{ V}$	1.0	1.4	3.0	A
		$V_{IN} = 16\text{ V}$	1.3	1.7	2.8	
Temperature Coefficient of Output Voltage	$\Delta V_O/\Delta T$	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $I_O = 5\text{ mA}$		-0.4		mV/°C

μPC2905 ($T_J = 25^\circ\text{C}$, $V_{IN} = 8\text{ V}$, $I_o = 500\text{ mA}$, $C_{IN} = 0.22\ \mu\text{F}$, $C_{OUT} = 47\ \mu\text{F}$, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	V_O		4.8	5.0	5.2	V
		$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $6\text{ V} \leq V_{IN} \leq 16\text{ V}$, $0\text{ A} \leq I_o \leq 500\text{ mA}$	4.75		5.25	
		$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $0\text{ A} \leq I_o \leq 1\text{ A}$				
Line Regulation	REG_{IN}	$6\text{ V} \leq V_{IN} \leq 16\text{ V}$		23	50	mV
Load Regulation	REG_L	$0\text{ A} \leq I_o \leq 1\text{ A}$		28	50	mV
Quiescent Current	I_{BIAS}	$I_o = 0\text{ A}$		2.2	4.0	mA
		$I_o = 1\text{ A}$		30	60	
Startup Quiescent Current	$I_{BIAS(s)}$	$V_{IN} = 4.5\text{ V}$, $I_o = 0\text{ A}$		10	30	mA
		$V_{IN} = 4.5\text{ V}$, $I_o = 1\text{ A}$			80	
Quiescent Current Change	ΔI_{BIAS}	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $6\text{ V} \leq V_{IN} \leq 16\text{ V}$		2.9	20	mA
Output Noise Voltage	V_n	$10\text{ Hz} \leq f \leq 100\text{ kHz}$		90		$\mu\text{V}_{r.m.s.}$
Ripple Rejection	R-R	$f = 120\text{ Hz}$, $6\text{ V} \leq V_{IN} \leq 16\text{ V}$	46	61		dB
Dropout Voltage	V_{DIF}	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $I_o = 1\text{ A}$		0.7	1.0	V
Short Circuit Current	$I_{O\ short}$	$V_{IN} = 6.5\text{ V}$	1.15	1.8	3.0	A
		$V_{IN} = 16\text{ V}$		1.1		
Peak Output Current	$I_{O\ peak}$	$V_{IN} = 6.5\text{ V}$	1.1	1.5	3.0	A
		$V_{IN} = 16\text{ V}$	1.4	2.0	2.8	
Temperature Coefficient of Output Voltage	$\Delta V_O/\Delta T$	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $I_o = 5\text{ mA}$		0.6		$\text{mV}/^\circ\text{C}$

μPC2906 ($T_J = 25^\circ\text{C}$, $V_{IN} = 9\text{ V}$, $I_O = 500\text{ mA}$, $C_{IN} = 0.22\ \mu\text{F}$, $C_{OUT} = 47\ \mu\text{F}$, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	V_O		5.76	6.0	6.24	V
		$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $7\text{ V} \leq V_{IN} \leq 16\text{ V}$, $0\text{ A} \leq I_O \leq 500\text{ mA}$	5.70		6.30	
		$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $0\text{ A} \leq I_O \leq 1\text{ A}$				
Line Regulation	REG_{IN}	$7\text{ V} \leq V_{IN} \leq 16\text{ V}$		25	60	mV
Load Regulation	REG_L	$0\text{ A} \leq I_O \leq 1\text{ A}$		29	60	mV
Quiescent Current	I_{BIAS}	$I_O = 0\text{ A}$		2.0	4.0	mA
		$I_O = 1\text{ A}$		23	60	
Startup Quiescent Current	$I_{BIAS(s)}$	$V_{IN} = 5.5\text{ V}$, $I_O = 0\text{ A}$		10	30	mA
		$V_{IN} = 5.5\text{ V}$, $I_O = 1\text{ A}$			80	
Quiescent Current Change	ΔI_{BIAS}	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $7\text{ V} \leq V_{IN} \leq 16\text{ V}$		2.2	20	mA
Output Noise Voltage	V_n	$10\text{ Hz} \leq f \leq 100\text{ kHz}$		108		$\mu\text{V}_{r.m.s.}$
Ripple Rejection	R·R	$f = 120\text{ Hz}$, $7\text{ V} \leq V_{IN} \leq 16\text{ V}$	44	60		dB
Dropout Voltage	V_{DIF}	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $I_O = 1\text{ A}$		0.7	1.0	V
Short Circuit Current	$I_{O\text{ short}}$	$V_{IN} = 7.5\text{ V}$		1.8		A
		$V_{IN} = 16\text{ V}$		1.1		
Peak Output Current	$I_{O\text{ peak}}$	$V_{IN} = 7.5\text{ V}$	1.1	1.5	3.0	A
		$V_{IN} = 16\text{ V}$	1.4	2.0	2.8	
Temperature Coefficient of Output Voltage	$\Delta V_O/\Delta T$	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $I_O = 5\text{ mA}$		0.6		$\text{mV}/^\circ\text{C}$

μPC2907 ($T_J = 25^\circ\text{C}$, $V_{IN} = 10\text{ V}$, $I_O = 500\text{ mA}$, $C_{IN} = 0.22\ \mu\text{F}$, $C_{OUT} = 47\ \mu\text{F}$, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	V_O		6.72	7.0	7.28	V
		$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $8\text{ V} \leq V_{IN} \leq 16\text{ V}$, $0\text{ A} \leq I_O \leq 500\text{ mA}$	6.65		7.35	
		$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $0\text{ A} \leq I_O \leq 1\text{ A}$				
Line Regulation	REG_{IN}	$8\text{ V} \leq V_{IN} \leq 16\text{ V}$		27	70	mV
Load Regulation	REG_L	$0\text{ A} \leq I_O \leq 1\text{ A}$		30	70	mV
Quiescent Current	I_{BIAS}	$I_O = 0\text{ A}$		2.0	4.0	mA
		$I_O = 1\text{ A}$		24	60	
Startup Quiescent Current	$I_{BIAS(s)}$	$V_{IN} = 6.5\text{ V}$, $I_O = 0\text{ A}$		10	30	mA
		$V_{IN} = 6.5\text{ V}$, $I_O = 1\text{ A}$			80	
Quiescent Current Change	ΔI_{BIAS}	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $8\text{ V} \leq V_{IN} \leq 16\text{ V}$		2.3	20	mA
Output Noise Voltage	V_n	$10\text{ Hz} \leq f \leq 100\text{ kHz}$		126		$\mu\text{V}_{r.m.s.}$
Ripple Rejection	R-R	$f = 120\text{ Hz}$, $8\text{ V} \leq V_{IN} \leq 16\text{ V}$	43	59		dB
Dropout Voltage	V_{DIF}	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $I_O = 1\text{ A}$		0.7	1.0	V
Short Circuit Current	$I_{O\text{ short}}$	$V_{IN} = 8.5\text{ V}$		1.8		A
		$V_{IN} = 16\text{ V}$		1.1		
Peak Output Current	$I_{O\text{ peak}}$	$V_{IN} = 8.5\text{ V}$	1.1	1.5	3.0	A
		$V_{IN} = 16\text{ V}$	1.4	2.0	2.8	
Temperature Coefficient of Output Voltage	$\Delta V_O/\Delta T$	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $I_O = 5\text{ mA}$		0.6		$\text{mV}/^\circ\text{C}$

μ PC2908 ($T_J = 25^\circ\text{C}$, $V_{IN} = 11\text{ V}$, $I_O = 500\text{ mA}$, $C_{IN} = 0.22\ \mu\text{F}$, $C_{OUT} = 47\ \mu\text{F}$, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	V_O		7.68	8.0	8.32	V
		$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $9\text{ V} \leq V_{IN} \leq 18\text{ V}$, $0\text{ A} \leq I_O \leq 500\text{ mA}$	7.6		8.4	
		$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $0\text{ A} \leq I_O \leq 1\text{ A}$				
Line Regulation	REG_{IN}	$9\text{ V} \leq V_{IN} \leq 18\text{ V}$		31	80	mV
Load Regulation	REG_L	$0\text{ A} \leq I_O \leq 1\text{ A}$		30	80	mV
Quiescent Current	I_{BIAS}	$I_O = 0\text{ A}$		1.9	4.0	mA
		$I_O = 1\text{ A}$		25	60	
Startup Quiescent Current	$I_{BIAS(s)}$	$V_{IN} = 7.5\text{ V}$, $I_O = 0\text{ A}$		10	30	mA
		$V_{IN} = 7.5\text{ V}$, $I_O = 1\text{ A}$			80	
Quiescent Current Change	ΔI_{BIAS}	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $9\text{ V} \leq V_{IN} \leq 18\text{ V}$		2.4	20	mA
Output Noise Voltage	V_n	$10\text{ Hz} \leq f \leq 100\text{ kHz}$		145		$\mu\text{V}_{r.m.s.}$
Ripple Rejection	R·R	$f = 120\text{ Hz}$, $9\text{ V} \leq V_{IN} \leq 18\text{ V}$	42	58		dB
Dropout Voltage	V_{DIF}	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $I_O = 1\text{ A}$		0.7	1.0	V
Short Circuit Current	$I_{O\text{ short}}$	$V_{IN} = 9.5\text{ V}$		1.9		A
		$V_{IN} = 18\text{ V}$		1.0		
Peak Output Current	$I_{O\text{ peak}}$	$V_{IN} = 9.5\text{ V}$	1.1	1.5	3.0	A
		$V_{IN} = 18\text{ V}$	1.4	2.0	2.8	
Temperature Coefficient of Output Voltage	$\Delta V_O/\Delta T$	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $I_O = 5\text{ mA}$		0.6		mV/ $^\circ\text{C}$

μPC2909 ($T_J = 25^\circ\text{C}$, $V_{IN} = 12\text{ V}$, $I_O = 500\text{ mA}$, $C_{IN} = 0.22\ \mu\text{F}$, $C_{OUT} = 47\ \mu\text{F}$, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	V_O		8.64	9.0	9.36	V
		$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $10\text{ V} \leq V_{IN} \leq 18\text{ V}$, $0\text{ A} \leq I_O \leq 500\text{ mA}$	8.55		9.45	
		$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $0\text{ A} \leq I_O \leq 1\text{ A}$				
Line Regulation	REG_{IN}	$10\text{ V} \leq V_{IN} \leq 18\text{ V}$		31	90	mV
Load Regulation	REG_L	$0\text{ A} \leq I_O \leq 1\text{ A}$		32	90	mV
Quiescent Current	I_{BIAS}	$I_O = 0\text{ A}$		1.9	4.0	mA
		$I_O = 1\text{ A}$		27	60	
Startup Quiescent Current	$I_{BIAS(s)}$	$V_{IN} = 8.5\text{ V}$, $I_O = 0\text{ A}$		11	30	mA
		$V_{IN} = 8.5\text{ V}$, $I_O = 1\text{ A}$			80	
Quiescent Current Change	ΔI_{BIAS}	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $10\text{ V} \leq V_{IN} \leq 18\text{ V}$		3.0	20	mA
Output Noise Voltage	V_n	$10\text{ Hz} \leq f \leq 100\text{ kHz}$		155		$\mu\text{V}_{r.m.s.}$
Ripple Rejection	R-R	$f = 120\text{ Hz}$, $10\text{ V} \leq V_{IN} \leq 18\text{ V}$	41	58		dB
Dropout Voltage	V_{DIF}	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $I_O = 1\text{ A}$		0.7	1.0	V
Short Circuit Current	$I_{O\text{ short}}$	$V_{IN} = 10.5\text{ V}$		1.9		A
		$V_{IN} = 18\text{ V}$		1.0		
Peak Output Current	$I_{O\text{ peak}}$	$V_{IN} = 10.5\text{ V}$	1.1	1.5	3.0	A
		$V_{IN} = 18\text{ V}$	1.4	2.0	3.0	
Temperature Coefficient of Output Voltage	$\Delta V_O/\Delta T$	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $I_O = 5\text{ mA}$		1.0		$\text{mV}/^\circ\text{C}$

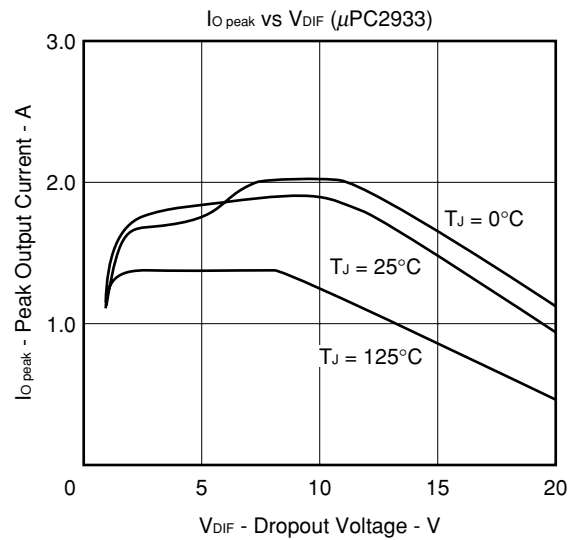
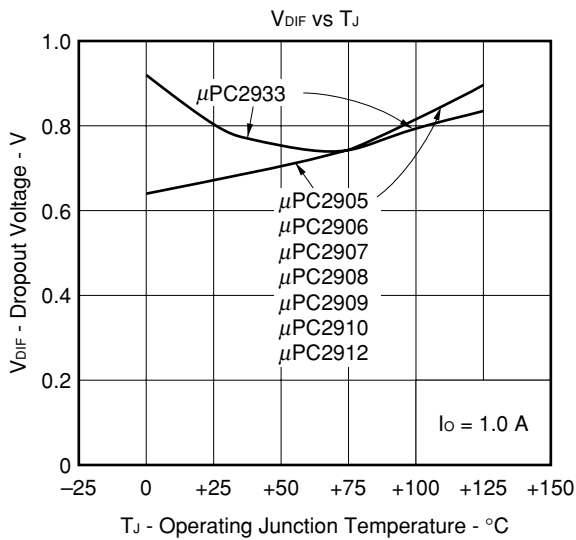
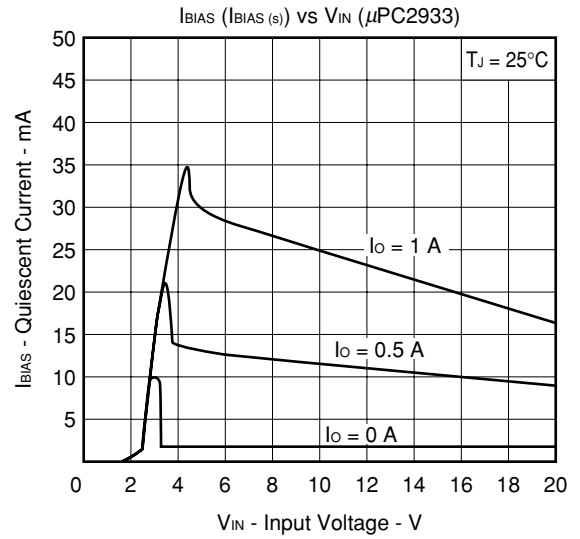
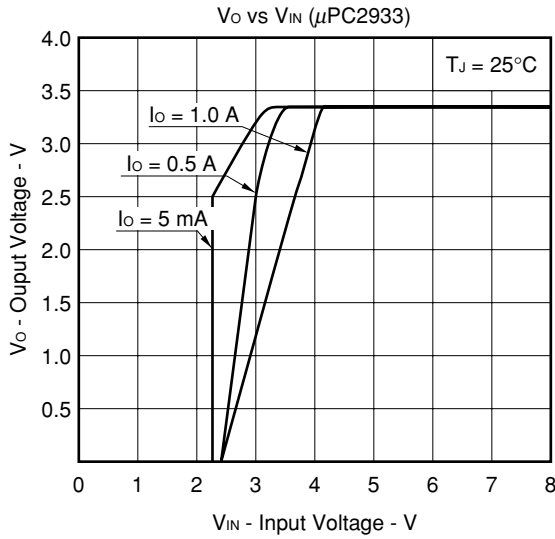
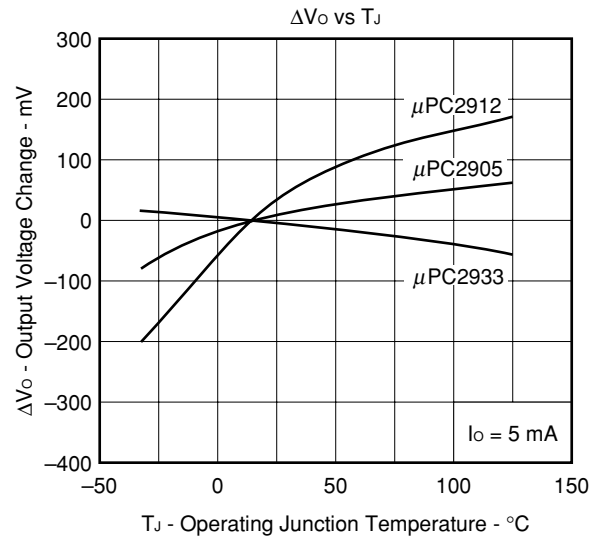
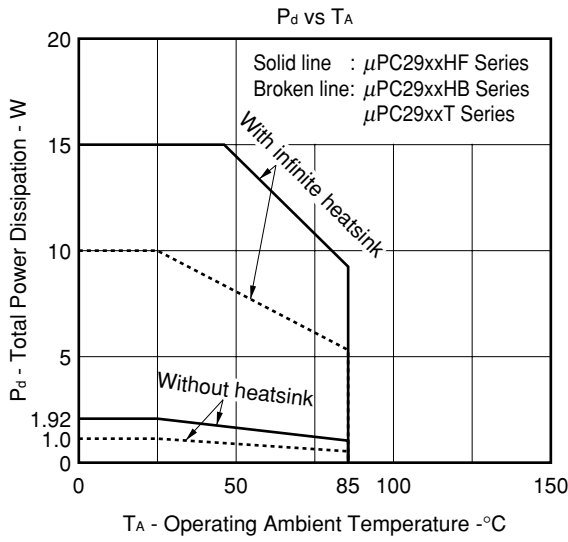
μPC2910 ($T_J = 25^\circ\text{C}$, $V_{IN} = 13\text{ V}$, $I_O = 500\text{ mA}$, $C_{IN} = 0.22\ \mu\text{F}$, $C_{OUT} = 47\ \mu\text{F}$, unless otherwise specified.)

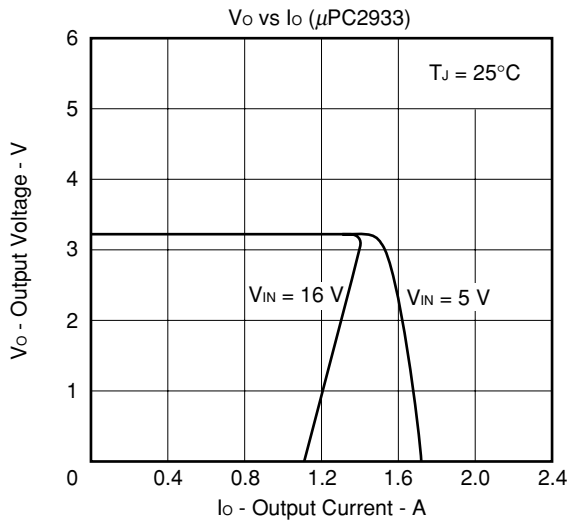
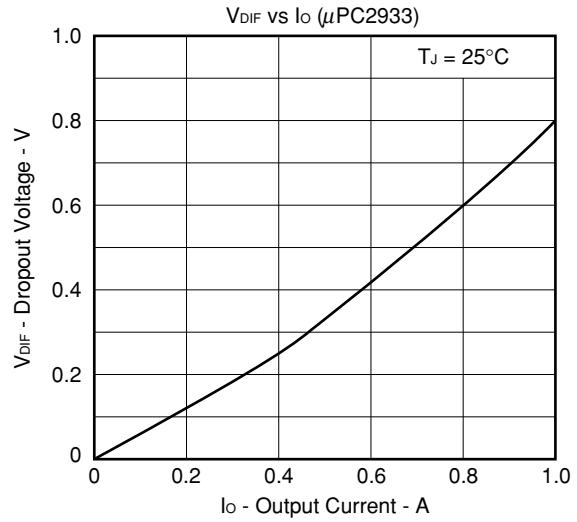
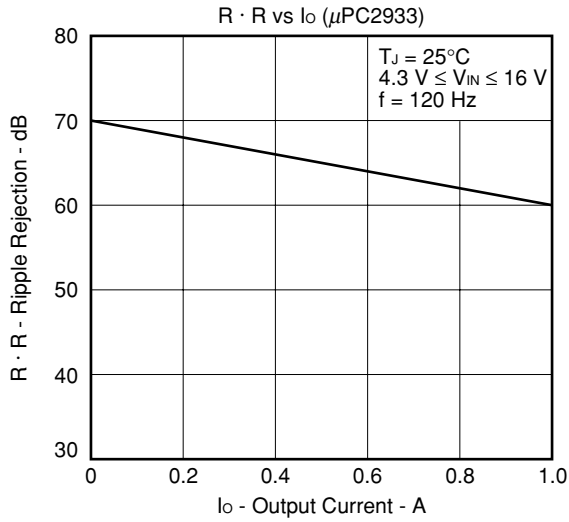
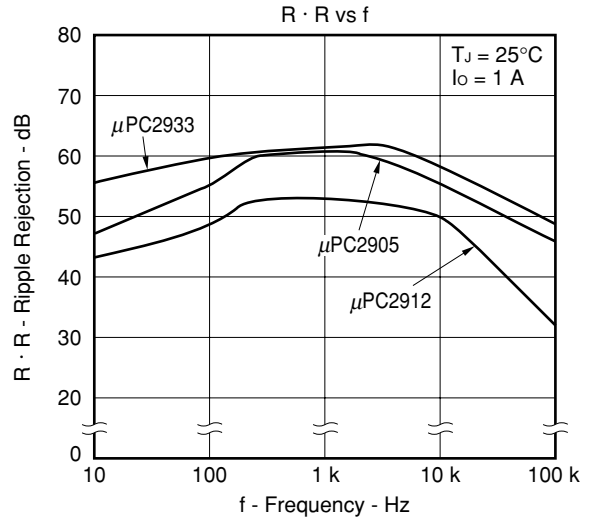
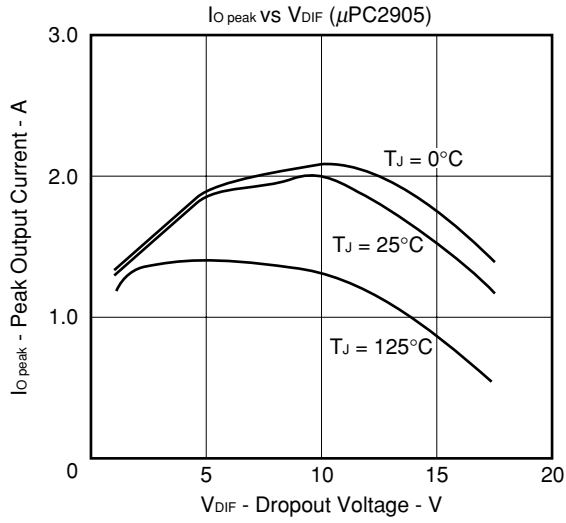
Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	V_O		9.6	10.0	10.4	V
		$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $11\text{ V} \leq V_{IN} \leq 18\text{ V}$, $0\text{ A} \leq I_O \leq 500\text{ mA}$	9.5		10.5	
		$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $0\text{ A} \leq I_O \leq 1\text{ A}$				
Line Regulation	REG_{IN}	$11\text{ V} \leq V_{IN} \leq 18\text{ V}$		35	100	mV
Load Regulation	REG_L	$0\text{ A} \leq I_O \leq 1\text{ A}$		33	100	mV
Quiescent Current	I_{BIAS}	$I_O = 0\text{ A}$		2.0	4.0	mA
		$I_O = 1\text{ A}$		25	60	
Startup Quiescent Current	$I_{BIAS(s)}$	$V_{IN} = 9.5\text{ V}$, $I_O = 0\text{ A}$		10	30	mA
		$V_{IN} = 9.5\text{ V}$, $I_O = 1\text{ A}$			80	
Quiescent Current Change	ΔI_{BIAS}	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $11\text{ V} \leq V_{IN} \leq 18\text{ V}$		1.9	20	mA
Output Noise Voltage	V_n	$10\text{ Hz} \leq f \leq 100\text{ kHz}$		180		$\mu\text{V}_{r.m.s.}$
Ripple Rejection	R·R	$f = 120\text{ Hz}$, $11\text{ V} \leq V_{IN} \leq 18\text{ V}$	40	56		dB
Dropout Voltage	V_{DIF}	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $I_O = 1\text{ A}$		0.7	1.0	V
Short Circuit Current	$I_{O\text{ short}}$	$V_{IN} = 11.5\text{ V}$		1.7		A
		$V_{IN} = 18\text{ V}$		1.0		
Peak Output Current	$I_{O\text{ peak}}$	$V_{IN} = 11.5\text{ V}$	1.1	1.6	3.0	A
		$V_{IN} = 18\text{ V}$	1.4	2.0	3.0	
Temperature Coefficient of Output Voltage	$\Delta V_O/\Delta T$	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $I_O = 5\text{ mA}$		2.1		mV/°C

μPC2912 ($T_J = 25^\circ\text{C}$, $V_{IN} = 15\text{ V}$, $I_O = 500\text{ mA}$, $C_{IN} = 0.22\ \mu\text{F}$, $C_{OUT} = 47\ \mu\text{F}$, unless otherwise specified.)

Parameters	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Output Voltage	V_O		11.52	12	12.48	V
		$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $13\text{ V} \leq V_{IN} \leq 18\text{ V}$, $0\text{ A} \leq I_O \leq 500\text{ mA}$	11.4		12.6	
		$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $0\text{ A} \leq I_O \leq 1\text{ A}$				
Line Regulation	REG_{IN}	$13\text{ V} \leq V_{IN} \leq 18\text{ V}$		38	120	mV
Load Regulation	REG_L	$0\text{ A} \leq I_O \leq 1\text{ A}$		35	120	mV
Quiescent Current	I_{BIAS}	$I_O = 0\text{ A}$		2.1	4.0	mA
		$I_O = 1\text{ A}$		26	60	
Startup Quiescent Current	$I_{BIAS(s)}$	$V_{IN} = 11.5\text{ V}$, $I_O = 0\text{ A}$		10	30	mA
		$V_{IN} = 11.5\text{ V}$, $I_O = 1\text{ A}$			80	
Quiescent Current Change	ΔI_{BIAS}	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $13\text{ V} \leq V_{IN} \leq 18\text{ V}$		1.5	20	mA
Output Noise Voltage	V_n	$10\text{ Hz} \leq f \leq 100\text{ kHz}$		210		$\mu\text{V}_{r.m.s.}$
Ripple Rejection	R-R	$f = 120\text{ Hz}$, $13\text{ V} \leq V_{IN} \leq 18\text{ V}$	40	52		dB
Dropout Voltage	V_{DIF}	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $I_O = 1\text{ A}$		0.7	1.0	V
Short Circuit Current	$I_{O\text{ short}}$	$V_{IN} = 14\text{ V}$		1.7		A
		$V_{IN} = 18\text{ V}$		1.0		
Peak Output Current	$I_{O\text{ peak}}$	$V_{IN} = 14\text{ V}$	1.1	1.6	3.0	A
		$V_{IN} = 18\text{ V}$	1.4	2.0	3.0	
Temperature Coefficient of Output Voltage	$\Delta V_O/\Delta T$	$0^\circ\text{C} \leq T_J \leq 125^\circ\text{C}$, $I_O = 5\text{ mA}$		2.1		$\text{mV}/^\circ\text{C}$

TYPICAL CHARACTERISTICS

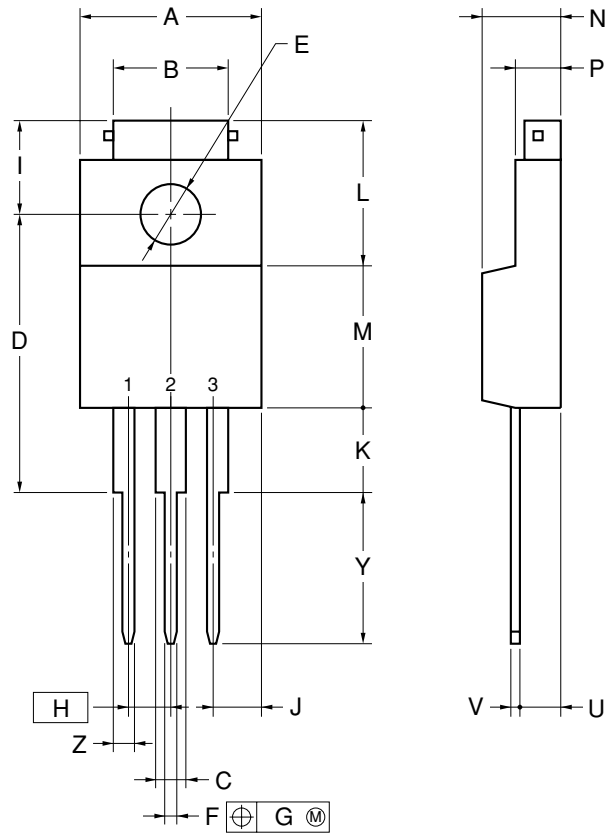




PACKAGE DRAWINGS

μPC29xxHF Series

3PIN PLASTIC SIP (MP-45G)



NOTE

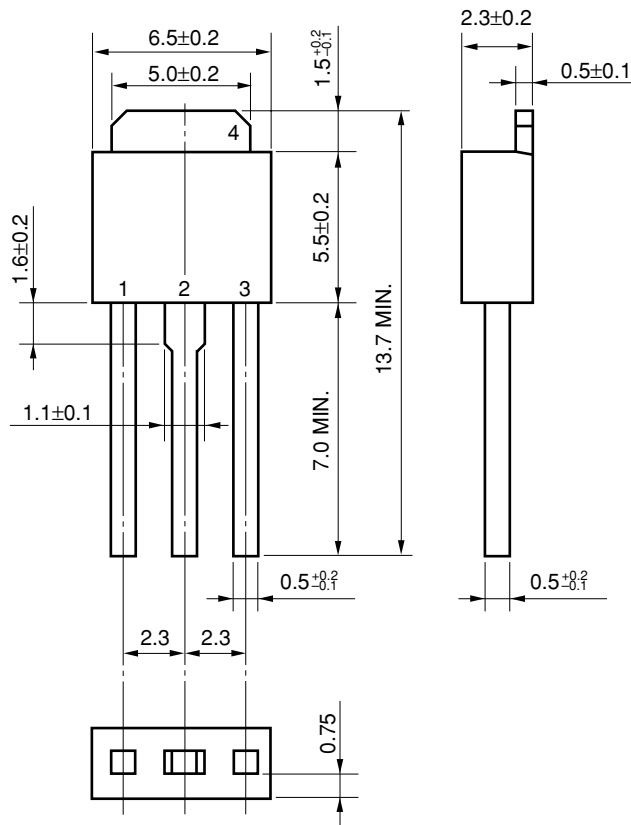
Each lead centerline is located within 0.25 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS
A	10.0±0.2
B	7.0±0.2
C	1.50±0.2
D	17.0±0.3
E	∅3.3±0.2
F	0.75±0.10
G	0.25
H	2.54 (T.P.)
I	5.0±0.3
J	2.46±0.2
K	5.0±0.2
L	8.5±0.2
M	8.5±0.2
N	4.5±0.2
P	2.8±0.2
U	2.4±0.5
V	0.65±0.10
Y	8.9±0.7
Z	1.30±0.2

P3HF-254B-4

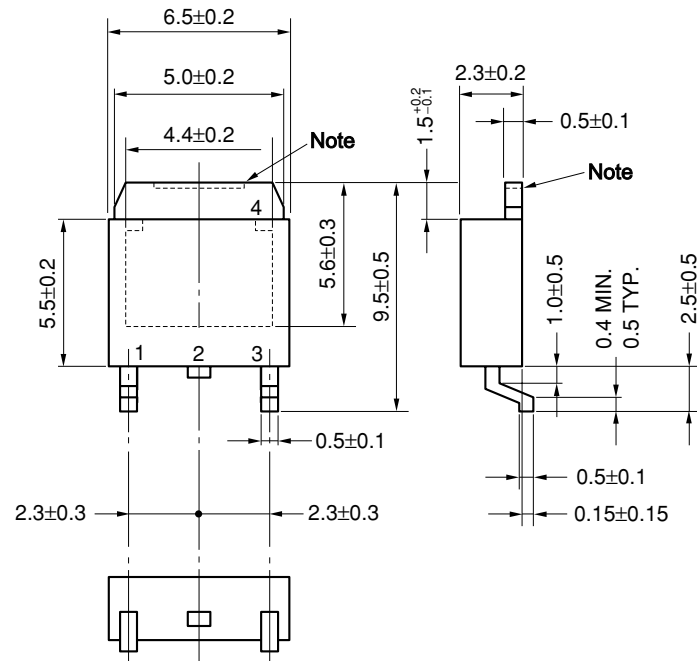
μPC29xxHB Series

SC-64 (MP-3) (Unit: mm)



μPC29xxT Series

<R> SC-63 (MP-3Z) (Unit: mm)



<R> **RECOMMENDED SOLDERING CONDITIONS**

When soldering this product, it is highly recommended to observe the conditions as shown below. If other soldering processes are used, or if the soldering is performed under different condition, please make sure to consult with our sales offices.

For more details, refer to the **Semiconductor Device Mount Manual**
 (<http://www.necel.com/pkg/en/mount/index.html>)

Surface mount devices

PC29xxT Series: SC-63 (MP-3Z)

Process	Conditions	Symbol
Infrared ray reflow	Peak temperature: 235°C or below (Package surface temperature), Reflow time: 30 seconds or less (at 210°C or higher), Maximum number of reflow processes: 3 times or less.	IR35-00-3
VPS	Peak temperature: 215°C or below (Package surface temperature), Reflow time: 40 seconds or less (at 200°C or higher), Maximum number of reflow processes: 3 times or less.	VP15-00-3
Partial heating method	Pin temperature: 350°C or below, Heat time: 3 seconds or less (Per each side of the device).	P350

Caution Apply only one kind of soldering condition to a device, except for “partial heating method”, or the device will be damaged by heat stress.

Remark Flux: Rosin-based flux with low chlorine content (chlorine 0.2 Wt% or below) is recommended.

PC29xxT-AZ Series ^{Note1}, PC29xxT-AY Series ^{Note2}: SC-63 (MP-3Z)

Process	Conditions	Symbol
Infrared ray reflow	Peak temperature: 260°C or below (Package surface temperature), Reflow time: 60 seconds or less (at 220°C or higher), Maximum number of reflow processes: 3 times or less.	IR60-00-3
Partial heating method	Pin temperature: 350°C or below, Heat time: 3 seconds or less (Per each side of the device).	P350

Notes 1. Pb-free (This product does not contain Pb in the external electrode.)

2. Pb-free (This product does not contain Pb in the external electrode, Sn100% plating.)

Caution Apply only one kind of soldering condition to a device, except for “partial heating method”, or the device will be damaged by heat stress.

Remark Flux: Rosin-based flux with low chlorine content (chlorine 0.2 Wt% or below) is recommended.

Through-hole devices

μPC29xxHF Series, μPC29xxHF-AZ Series ^{Note1}: Isolated TO-220 (MP-45G)

μPC29xxHB Series, μPC29xxHB-AZ Series ^{Note1}, μPC29xxHB-AY Series ^{Note2}: SC-64 (MP-3)

Process	Conditions	Symbol
Wave soldering (only to leads)	Solder temperature: 260°C or below, Flow time: 10 seconds or less.	WS60-00-1
Partial heating method	Pin temperature: 350°C or below, Heat time: 3 seconds or less (Per each pin).	P350

Notes 1. Pb-free (This product does not contain Pb in the external electrode.)

2. Pb-free (This product does not contain Pb in the external electrode, Sn100% plating.)

Caution For through-hole device, the wave soldering process must be applied only to leads, and make sure that the package body does not get jet soldered.

CAUTION ON USE

When using the μPC29xx series at the input voltage which is lower than in the recommended operating condition, the high quiescent current flows through devices because the transistor of the output paragraph is saturated (Refer to “**I_{BIAS} (I_{BIAS(s)}) vs V_{IN} curves in TYPICAL CHARACTERISTICS**”). The μPC29xx series have saturation protection circuits, but they sometimes need about 80 mA current. Therefore the power supply on the input needs the enough current capacity to pass this quiescent current when the devices startup.

<R> **REFERENCE DOCUMENTS**

USER'S MANUAL USAGE OF THREE TERMINAL REGULATORS	Document No.G12702E
REVIEW OF QUALITY AND RELIABILITY HANDBOOK	Document No.C12769E
INFORMATION VOLTAGE REGULATOR OF SMD	Document No.G11872E
SEMICONDUCTOR DEVICE MOUNT MANUAL	http://www.necel.com/pkg/en/mount/index.html

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"Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support).

"Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

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